

TOSHIBA Field-Effect Transistor Silicon P-Channel MOS Type (U-MOSV)

SSM3J307T

- Power Management Switch Applications
- High-Speed Switching Applications

- 1.5 V drive
- Low ON-resistance: $R_{ON} = 83 \text{ m}\Omega$ (max) (@ $V_{GS} = -1.5 \text{ V}$)
 $R_{ON} = 56 \text{ m}\Omega$ (max) (@ $V_{GS} = -1.8 \text{ V}$)
 $R_{ON} = 40 \text{ m}\Omega$ (max) (@ $V_{GS} = -2.5 \text{ V}$)
 $R_{ON} = 31 \text{ m}\Omega$ (max) (@ $V_{GS} = -4.5 \text{ V}$)

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristic	Symbol	Rating	Unit
Drain-Source voltage	V_{DSS}	-20	V
Gate-Source voltage	V_{GSS}	± 8	V
Drain current	DC	I_D (Note 1)	A
	Pulse	I_{DP} (Note 1)	
Drain power dissipation	P_D (Note 2)	700	mW
	$t = 10 \text{ s}$	1250	
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55 to 150	$^\circ\text{C}$

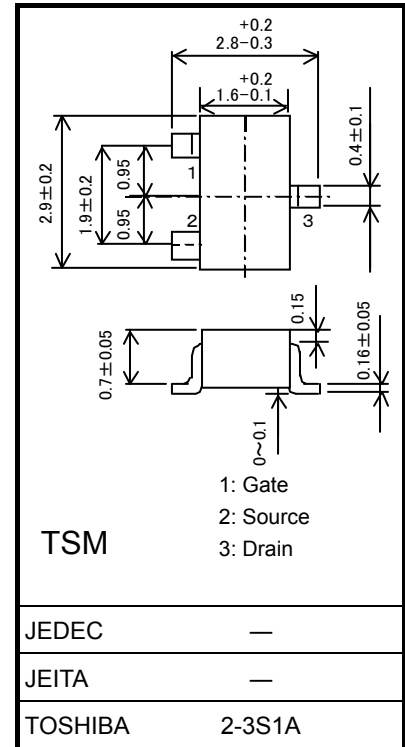
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: The junction temperature should not exceed 150°C during use.

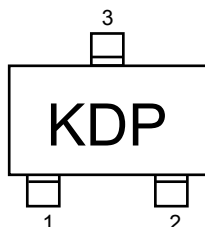
Note 2: Mounted on an FR4 board. (25.4 mm $\times$ 25.4 mm $\times$ 1.6 mm, Cu Pad: 645 mm²)

Unit: mm

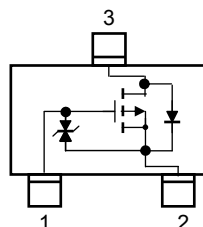


Weight: 10 mg (typ.)

Marking



Equivalent Circuit (top view)



Start of commercial production
2008-09

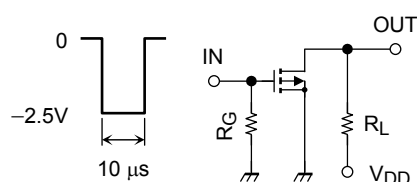
Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Conditions	Min	Typ.	Max	Unit
Drain-Source breakdown voltage	$V_{(BR)DSS}$	$I_D = -1 \text{ mA}$, $V_{GS} = 0 \text{ V}$	-20	—	—	V
	$V_{(BR)DSX}$	$I_D = -1 \text{ mA}$, $V_{GS} = +8 \text{ V}$	-12	—	—	
Drain cut-off current	I_{DSS}	$V_{DS} = -20 \text{ V}$, $V_{GS} = 0 \text{ V}$	—	—	-10	μA
Gate leakage current	I_{GSS}	$V_{GS} = \pm 8 \text{ V}$, $V_{DS} = 0 \text{ V}$	—	—	± 1	μA
Gate threshold voltage	V_{th}	$V_{DS} = -3 \text{ V}$, $I_D = -1 \text{ mA}$	-0.3	—	-1.0	V
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = -3 \text{ V}$, $I_D = -4.0 \text{ A}$ (Note 3)	9.8	—	—	S
Drain-source ON-resistance	$R_{DS(ON)}$	$I_D = -4.0 \text{ A}$, $V_{GS} = -4.5 \text{ V}$ (Note 3)	—	25	31	$\text{m}\Omega$
		$I_D = -4.0 \text{ A}$, $V_{GS} = -2.5 \text{ V}$ (Note 3)	—	31	40	
		$I_D = -1.5 \text{ A}$, $V_{GS} = -1.8 \text{ V}$ (Note 3)	—	38	56	
		$I_D = -0.75 \text{ A}$, $V_{GS} = -1.5 \text{ V}$ (Note 3)	—	46	83	
Input capacitance	C_{iss}	$V_{DS} = -10 \text{ V}$, $V_{GS} = 0 \text{ V}$, $f = 1 \text{ MHz}$	—	1170	—	pF
Output capacitance	C_{oss}		—	250	—	
Reverse transfer capacitance	C_{rss}		—	200	—	
Total Gate Charge	Q_g	$V_{DS} = -10 \text{ V}$, $I_D = -5.0 \text{ A}$ $V_{GS} = -4.5 \text{ V}$	—	19	—	nC
Gate-Source Charge	Q_{gs}		—	14.2	—	
Gate-Drain Charge	Q_{gd}		—	4.8	—	
Switching time	Turn-on time	$V_{DD} = -10 \text{ V}$, $I_D = -2.0 \text{ A}$, $V_{GS} = 0 \text{ to } -2.5 \text{ V}$, $R_G = 4.7 \Omega$	—	35	—	ns
	Turn-off time		—	160	—	
Drain-Source forward voltage	V_{DSF}	$I_D = 5.0 \text{ A}$, $V_{GS} = 0 \text{ V}$ (Note 3)	—	0.83	1.2	V

Note 3: Pulse test

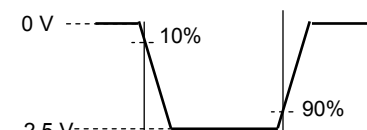
Switching Time Test Circuit

(a) Test Circuit

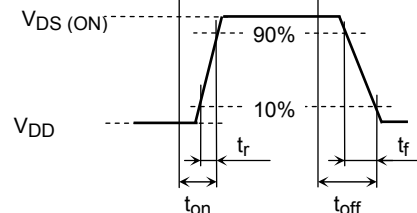


$V_{DD} = -10 \text{ V}$
 $R_G = 4.7 \Omega$
 Duty $\leq 1\%$
 V_{IN} : $t_r, t_f < 5 \text{ ns}$
 Common Source
 $T_a = 25^\circ\text{C}$

(b) V_{IN}



(c) V_{OUT}



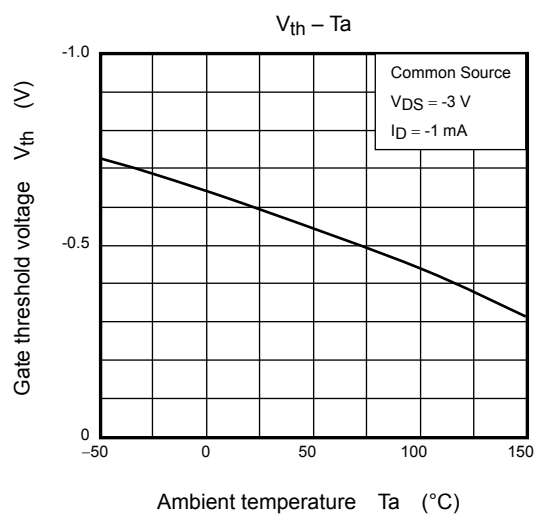
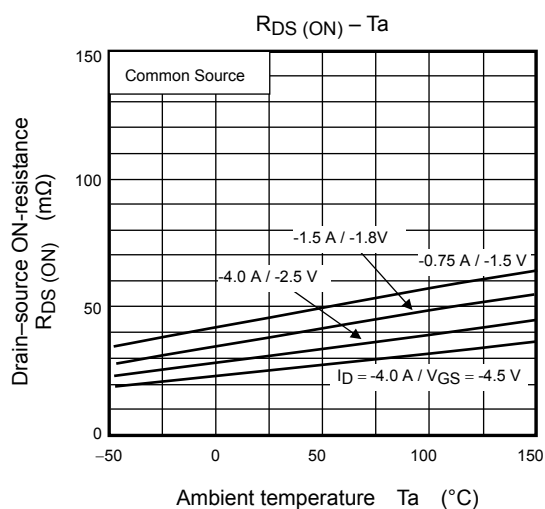
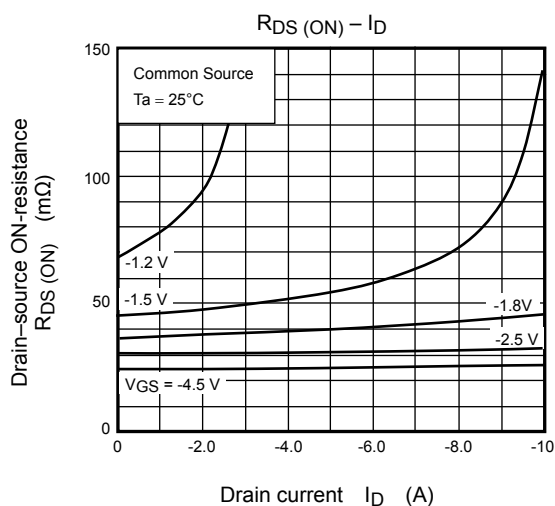
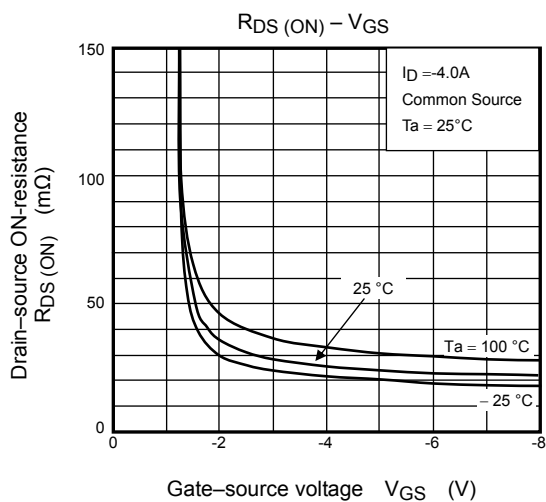
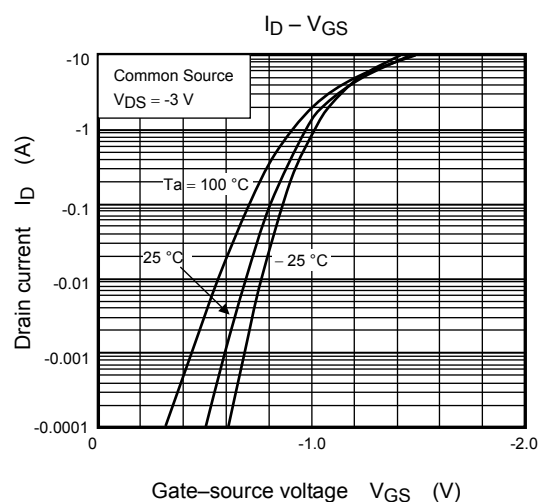
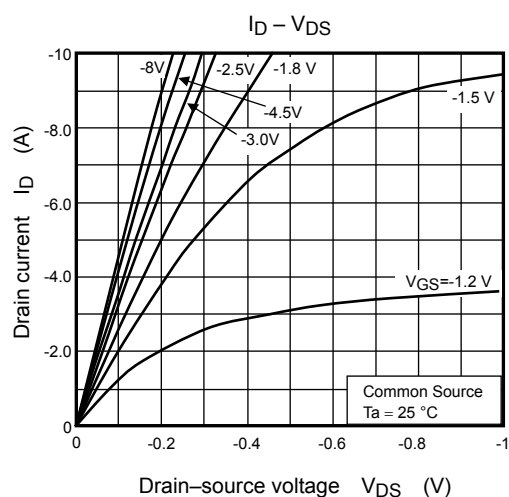
Usage Considerations

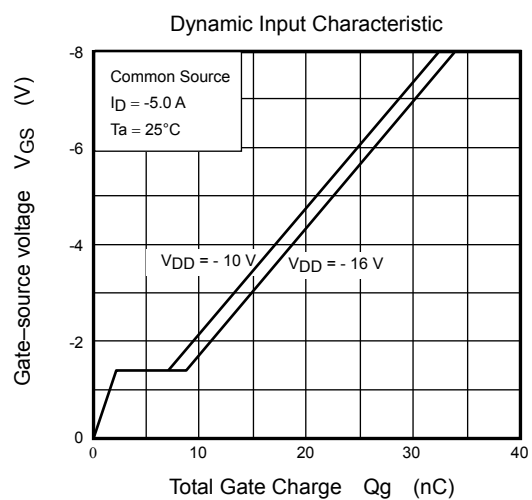
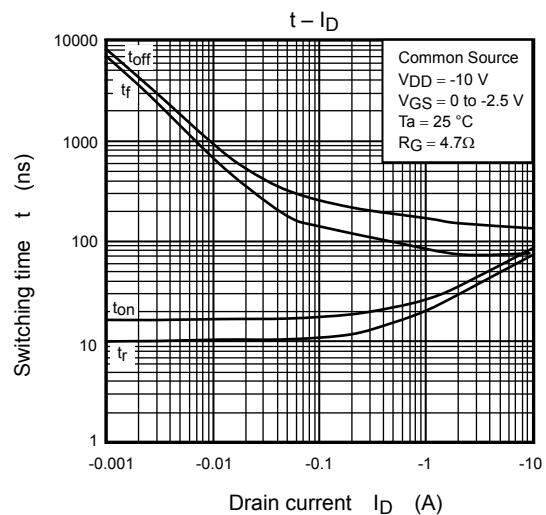
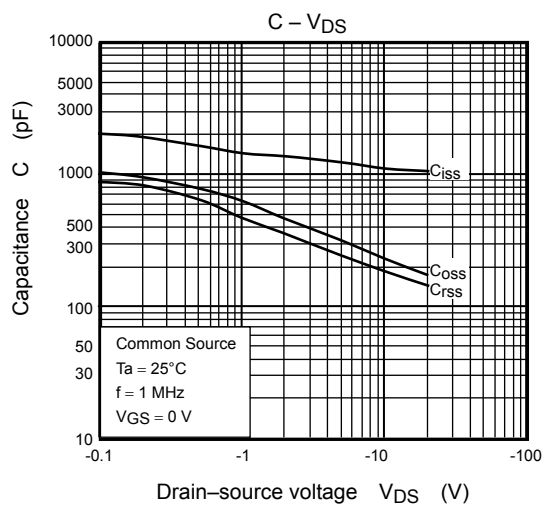
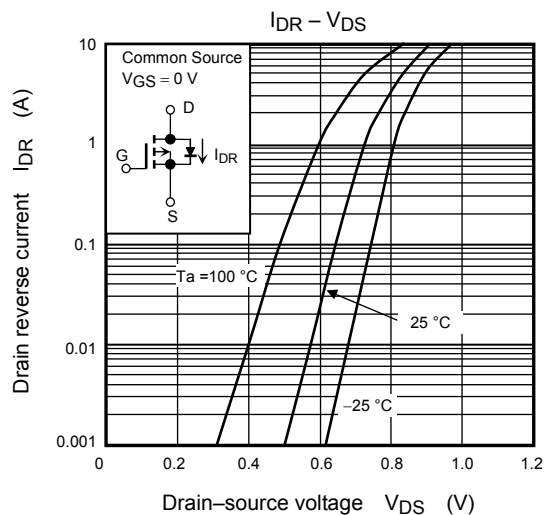
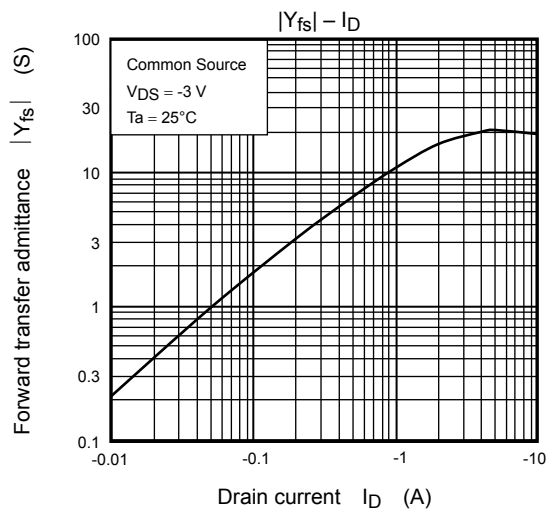
Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below -1 mA for the SSM3J307T. Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th} , and $V_{GS(off)}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$.

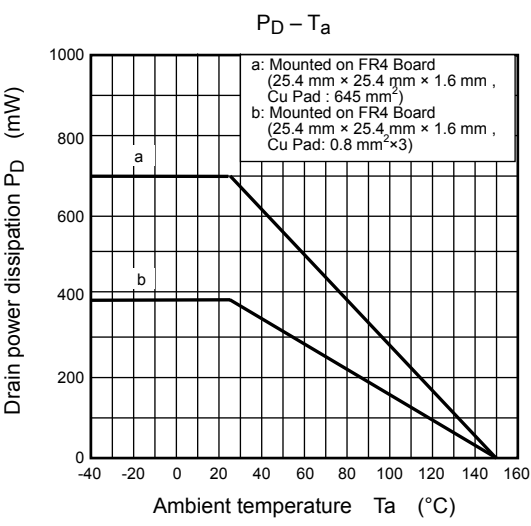
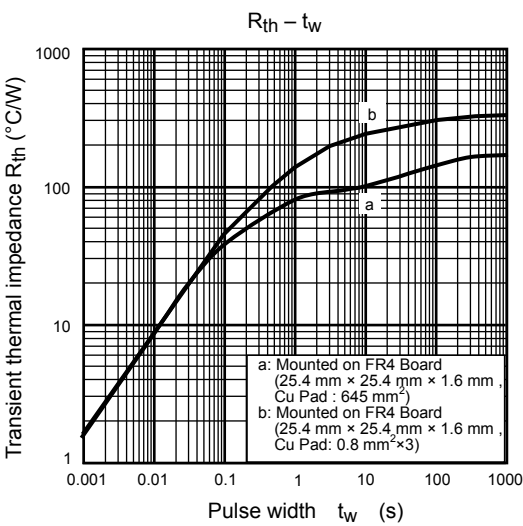
Take this into consideration when using the device.

Handling Precaution

When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.







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